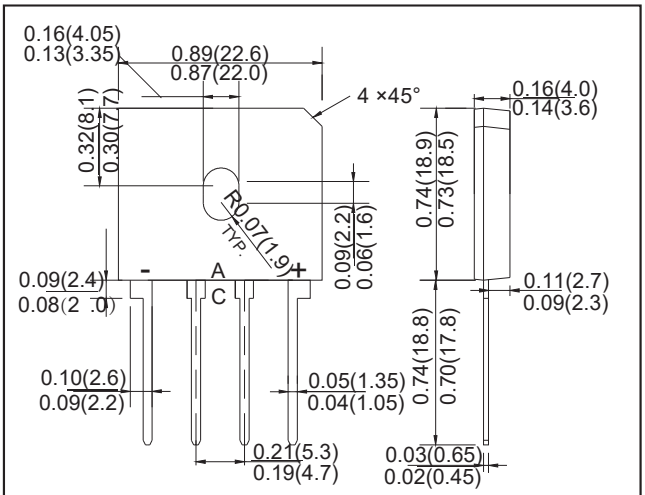
GBU SILICON BRIDGE RECTIFIERV

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed:260 ℃/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style:GUB molded plastic
- Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		GBU 25A	GBU 25B	GBU 25D	GBU 25G	GBU 25J	GBU 25K	GBU 25M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forw ard Tc=100℃ output current	$I_{F(AV)}$	25.0							A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I_{FSM}	340							A
Maximum instantaneous forw ard voltage at 12.5 A	V_F	1.0							V
Maximum reverse current @T_A=25℃	I_R	5.0							μA
at rated DC blocking voltage @T_A=125℃		500.0							mA
Typical junction capacitance per leg	C_J	211				94			pF
Typical thermal resistance per leg	$R_{\theta JA}$	21.0							℃/W
	$R_{\theta JC}$	2.2							
Operating junction temperature range	T_J	- 55 ---- + 150							℃
Storage temperature range	T_{STG}	- 55 ---- + 150							℃

RATINGS AND CHARACTERISTIC CURVES

FIG.1 – DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

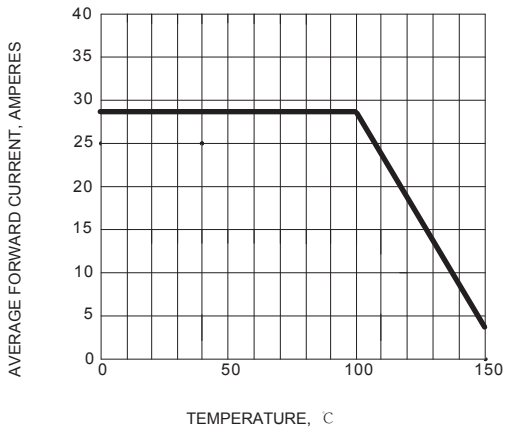


FIG.2 – TYPICAL FORWARD CHARACTERISTIC

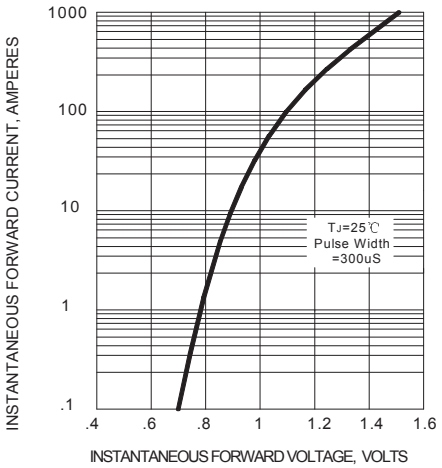


FIG.3 – MAXIMUM NON-REPETITIVE PEAK FORWARD DURGE CURRENT

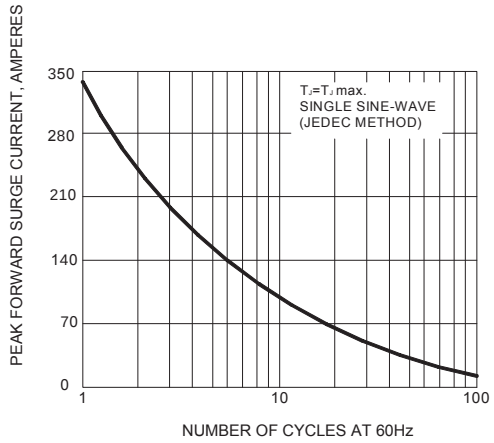


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

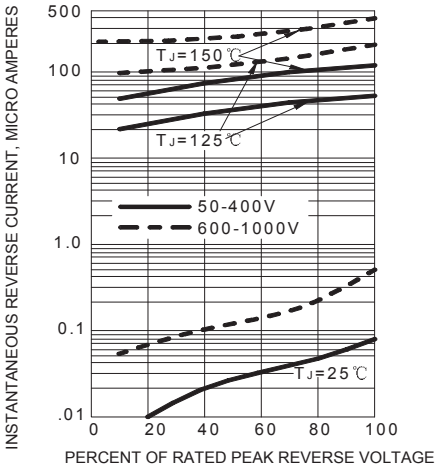


FIG.5 – TYPICAL JUNCTION CAPACITANCE PER LEG

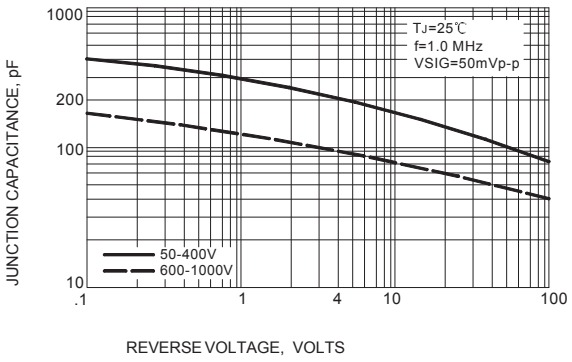


FIG.6 – TYPICAL TRANSIENT THERMAL IMPEDANCE